

# IPG20N04S4L11AATMA1

### IPG20N04S4L11AATMA1 Information





Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



### IPG20N04S4L11AATMA1 Specifications

	Report errors?
Supplier Device Package	PG-TDSON-8-10
Package / Case	8-PowerVDFN
Mounting Type	Surface Mount
Operating Temperature	-55°C ~ 175°C (TJ)
Power - Max	41W
Input Capacitance (Ciss) (Max) @ Vds	1990pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	26nC @ 10V
Vgs(th) (Max) @ Id	2.2V @ 15µA
Rds On (Max) @ Id, Vgs	11.6 mOhm @ 17A, 10V
Current - Continuous Drain (Id) @ 25°C	20A
Drain to Source Voltage (Vdss)	40V
FET Feature	Logic Level Gate
FET Type	2 N-Channel (Dual)
Series	Automotive, AEC-Q101, OptiMOS?
Package	8-PowerVDFN
	Transistors - FETs, MOSFETs - Arrays
Category	Discrete Semiconductor Products
Manufacturer	Infineon Technologies
Manufacturer Part Number	IPG20N04S4L11AATMA1

### IPG20N04S4L11AATMA1 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### IPG20N04S4L11AATMA1 Payment Methods



If you have any question about IPG20N04S4L11AATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com